Single Buffer

The NL17SG34 MiniGate[™] is an advanced high-speed CMOS Buffer in ultra-small footprint.

The NL17SG34 input structures provides protection when voltages up to 4.6 V are applied.

Features

- Wide Operating V_{CC} Range: 0.9 V to 3.6 V
- High Speed: $t_{PD} = 2.3$ ns (Typ) at $V_{CC} = 3.0$ V, $C_L = 15$ pF
- Low Power Dissipation: $I_{CC} = 0.5 \mu A$ (Max) at $T_A = 25^{\circ}C$
- 4.6 V Overvoltage Tolerant (OVT) Input Pins
- Ultra-Small Packages
- These are Pb-Free and Halide-Free Devices

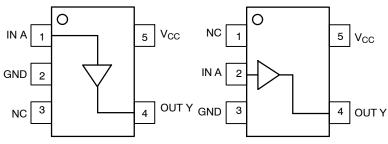


Figure 1. SOT-953 (Top Thru View)

Figure 2. SC-88A/TSOP-5 (Top View)

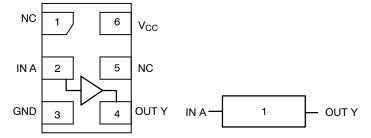


Figure 3. UDFN (Top View)

Figure 4. Logic Symbol



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MARKING DIAGRAMS



SOT-953 CASE 527AE



= Specific Device Code (D with 90 degree clockwise rotation)



UDFN6 1.0 x 1.0 CASE 517BX



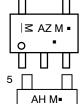


UDFN6 1.45 x 1.0 CASE 517AQ





SC-88A **DF SUFFIX** CASE 419A





TSOP-5 DT SUFFIX **CASE 483**





= Pb-Free Package (Note: Microdot may be in either location)

*Date Code orientation and/or position may vary depending upon manufacturing location.

| PIN ASSIGNMENT | | | | | | |
|----------------|-----------------|-------------|-----------------|--|--|--|
| | SOT-953 | SC88A/TSOP5 | UDFN6 | | | |
| 1 | IN A | NC | NC | | | |
| 2 | GND | IN A | IN A | | | |
| 3 | NC | GND | GND | | | |
| 4 | OUT Y | OUT Y | OUT Y | | | |
| 5 | V _{CC} | V_{CC} | NC | | | |
| 6 | | | V _{CC} | | | |

FUNCTION TABLE

| A Input | Y Output |
|---------|----------|
| L | L |
| Н | Н |

ORDERING INFORMATION

See detailed ordering and shipping information on page 5 of this data sheet.

MAXIMUM RATINGS

| Symbol | Parameter | | Value | Unit |
|----------------------|---|--|--|------|
| V _{CC} | DC Supply Voltage | | -0.5 to +5.5 | V |
| V _{IN} | DC Input Voltage | | -0.5 to +4.6 | V |
| V _{OUT} | DC Output Voltage | Output at High or Low State ower-Down Mode (V _{CC} = 0 V) | -0.5 to V _{CC} +0.5 -0.5 to +4.6 | V |
| I _{IK} | DC Input Diode Current | V _{IN} < GND | -20 | mA |
| lok | DC Output Diode Current | V _{OUT} < GND | -20 | mA |
| I _{OUT} | DC Output Source/Sink Current | | ±20 | mA |
| I _{CC} | DC Supply Current per Supply Pin | | ±20 | mA |
| I _{GND} | DC Ground Current per Ground Pin | | ±20 | mA |
| T _{STG} | Storage Temperature Range | | -65 to +150 | °C |
| T _L | Lead Temperature, 1 mm from Case for 10 Seconds | | 260 | °C |
| TJ | Junction Temperature Under Bias | | +150 | °C |
| MSL | Moisture Sensitivity | | Level 1 | |
| F _R | Flammability Rating | Oxygen Index: 28 to 34 | UL 94 V-0 @ 0.125 in | |
| V _{ESD} | ESD Withstand Voltage | Human Body Model (Note 2) Machine Model (Note 3) | >2000 >100 | V |
| I _{LATCHUP} | Latchup Performance Above V _{CC} and I | Below GND at 125°C (Note 4) | ±100 | mA |

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

Measured with minimum pad spacing on an FR4 board, using 10 mm-by-1 inch, 2-ounce copper trace with no air flow.

Tested to EIA/JESD22-A114-A.

Tested to EIA/JESD22-A115-A.

- 4. Tested to EIA/JESD78.

RECOMMENDED OPERATING CONDITIONS

| Symbol | Characteristics | Min | Max | Unit |
|------------------|--|-------------------|------------------------|------|
| V _{CC} | Positive DC Supply Voltage | 0.9 | 3.6 | V |
| V _{IN} | Digital Input Voltage | 0.0 | 3.6 | V |
| V _{OUT} | Output Voltage Output at High or Low St Power–Down Mode (V _{CC} = 0 | ate 0.0 V) 0.0 | V _{CC} 3.6 | V |
| T _A | Operating Temperature Range | -55 | +125 | °C |
| Δt / ΔV | Input Transition Rise or Fail Rate $V_{CC} = 3.3 \text{ V} \pm 0.0$ | 3 V 0 | 10 | ns/V |

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.

DC ELECTRICAL CHARACTERISTICS

| | | | | | T _A = | 25°C | | . = > +125°C | | | |
|-----------------|-----------------------------|---------------------------------------|------------------------------|---------------------------------------|------------------------------|------------------------------|----------------------|----------------------|----------------------|----------------------|--|
| Symbol | Parameter | C | onditions | V _{CC} (V) | Min | Max | Min | Max | Unit | | |
| V _{IH} | High-Level Input | | | 0.9 | V _{CC} | | V _{CC} | | V | | |
| | Voltage | | | 1.1 to 1.3 | 0.7xV _{CC} | | 0.7xV _{CC} | | | | |
| | | | | 1.4 to 1.6 | 0.65xV _{CC} | | 0.65xV _{CC} | | | | |
| | | | | 1.65 to 1.95 | 0.65xV _{CC} | | 0.65xV _{CC} | | | | |
| | | | | 2.3 to 2.7 | 1.7 | | 1.7 | | | | |
| | | | | 3.0 to 3.6 | 2.0 | | 2.0 | | | | |
| V_{IL} | Low-Level Input | | | 0.9 | | GND | | GND | V | | |
| | Voltage | | | 1.1 to 1.3 | | 0.3xV _{CC} | | 0.3xV _{CC} | | | |
| | | | | 1.4 to 1.6 | | 0.35xV _{CC} | | 0.35xV _{CC} | | | |
| | | | | 1.65 to 1.95 | | 0.35xV _{CC} | | 0.35xV _{CC} | | | |
| | | | | 2.3 to 2.7 | | 0.7 | | 0.7 | | | |
| | | | | 3.0 to 3.6 | | 0.8 | | 0.8 | | | |
| V _{OH} | High-Level | V _{IN} = | I _{OH} = -20 μA | 0.9 | 0.75 | | 0.75 | | V | | |
| | Output Voltage | Output Voltage | Output Voltage v | V _{IH} or V _{IL} | I _{OH} = -0.3 mA | 1.1 to 1.3 | 0.75xV _{CC} | | 0.75xV _{CC} | | |
| | | | | | | I _{OH} = −1.7 mA | 1.4 to 1.6 | 0.75xV _{CC} | | 0.75xV _{CC} | |
| | | | I _{OH} = −3.0 mA | 1.65 to 1.95 | Vcc-0.45 | | Vcc-0.45 | | | | |
| | | | I _{OH} = -4.0 mA | 2.3 to 2.7 | 2.0 | | 2.0 | | | | |
| | | | I _{OH} = -8.0 mA | 3.0 to 3.6 | 2.48 | | 2.48 | | | | |
| V _{OL} | Low-Level | V _{IN} = | I _{OL} = 20 μA | 0.9 | | 0.1 | | 0.1 | V | | |
| | Output Voltage | V _{IH} or V _{IL} | I _{OL} = 0.3 mA | 1.1 to 1.3 | | 0.25xV _{CC} | | 0.25xV _{CC} | | | |
| | | I _{OL} = 1.7 mA | I _{OL} = 1.7 mA | 1.4 to 1.6 | | 0.25xV _{CC} | | 0.25xV _{CC} | | | |
| | | | I _{OL} = 3.0 mA | 1.65 to 1.95 | | 0.45 | | 0.45 | | | |
| | | | I _{OL} = 4.0 mA | 2.3 to 2.7 | | 0.4 | | 0.4 | | | |
| | | | I _{OL} = 8.0 mA | 3.0 to 3.6 | | 0.4 | | 0.4 | | | |
| I _{IN} | Input Leakage Current | 0 ≤ | V _{IN} ≤ 3.6 V | 0 to 3.6 | | ±0.1 | | ±1.0 | μΑ | | |
| I _{CC} | Quiescent Supply Current | V _{IN} = | V _{CC} or GND | 3.6 | | 0.5 | | 10.0 | μΑ | | |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

AC ELECTRICAL CHARACTERISTICS Input $t_r = t_f = 3.0 \text{ ns}$

| Symbol | Parameter | Test Condition | V _{CC} (V) | T _A = 25° C | | | = 0 +125°C | | |
|--------------------|---|---|---------------------|------------------------|------|------|---------------|------|------|
| | | | | Min | Тур | Max | Min | Max | Unit |
| t _{PLH} , | Propagation Delay, | C _L = 10 pF, | 0.9 | - | 12.6 | 15.3 | - | 19.0 | ns |
| t _{PHL} | A to Y | $R_L = 1 M\Omega$ | 1.1 to 1.3 | - | 8.7 | 13.4 | - | 15.2 | |
| | | | 1.4 to 1.6 | - | 4.9 | 8.5 | - | 10.0 | |
| | | | 1.65 to 1.95 | - | 3.8 | 6.2 | - | 6.7 | |
| | | | 2.3 to 2.7 | _ | 2.6 | 3.9 | - | 4.4 | |
| | | | 3.0 to 3.6 | - | 2.1 | 3.1 | _ | 3.7 | |
| | | $C_L = 15 \text{ pF},$ $R_L = 1 \text{ M}\Omega$ | 0.9 | - | 13.0 | 16.6 | _ | 20.8 | ns |
| | | | 1.1 to 1.3 | - | 8.0 | 12.5 | _ | 15.7 | |
| | | | 1.4 to 1.6 | - | 5.4 | 9.3 | _ | 11.2 | |
| | | | 1.65 to 1.95 | - | 4.2 | 6.9 | _ | 7.1 | |
| | | | 2.3 to 2.7 | _ | 2.8 | 4.4 | - | 5.0 | |
| | | | 3.0 to 3.6 | _ | 2.3 | 3.4 | - | 3.9 | |
| | | $C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$ | 0.9 | _ | 14.5 | 17.6 | - | 22.4 | ns |
| | | | 1.1 to 1.3 | _ | 9.5 | 13.5 | - | 18.8 | |
| | | | 1.4 to 1.6 | _ | 7.4 | 11.1 | - | 15.9 | |
| | | | 1.65 to 1.95 | _ | 5.6 | 9.2 | - | 9.6 | |
| | | | 2.3 to 2.7 | _ | 3.7 | 5.7 | - | 6.1 | |
| | | | 3.0 to 3.6 | _ | 2.9 | 4.4 | - | 4.8 | |
| C _{IN} | Input Capacitance | | 0 to 3.6 | | 3 | - | - | - | pF |
| C _{PD} | Power Dissipation Capacitance (Note 5) | f = 10 MHz | 0.9 to 3.6 | _ | 4 | _ | _ | _ | pF |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

5. C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load. Average operating current can be obtained by the equation: $I_{CC(OPR)} = C_{PD} \bullet V_{CC} \bullet f_{in} + I_{CC} \cdot C_{PD}$ is used to determine the no–load dynamic power consumption; $P_D = C_{PD} \bullet V_{CC}^2 \bullet f_{in} + I_{CC} \bullet V_{CC}$.

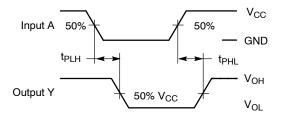
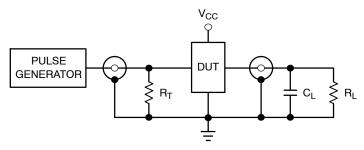


Figure 5. Switching Waveforms



 $R_T = Z_{OUT}$ of pulse generator (typically 50 Ω)

Figure 6. Test Circuit

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|-----------------|------------------------------|-----------------------|
| NL17SG34P5T5G | SOT-953 (Pb-Free) | 8000 / Tape & Reel |
| NL17SG34DFT2G | SC-88A (Pb-Free) | 3000 / Tape & Reel |
| NL17SG34DTT1G* | TSOP-5 (Pb-Free) | 3000 / Tape & Reel |
| NL17SG34AMUTCG* | UDFN6 1.45x1 mm (Pb-Free) | 3000 / Tape & Reel |
| NL17SG34CMUTCG* | UDFN6 1x1 mm (Pb-Free) | 3000 / Tape & Reel |

[†]For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

^{*}In Development



SC-88A (SC-70-5/SOT-353) CASE 419A-02 **ISSUE L**

DATE 17 JAN 2013



- TES:
 DIMENSIONING AND TOLERANCING
 PER ANSI Y14.5M, 1982.
 CONTROLLING DIMENSION: INCH.
 419A-01 OBSOLETE. NEW STANDARD 3.
- 419A-02.
 DIMENSIONS A AND B DO NOT INCLUDE MOLD FLASH, PROTRUSIONS, OR GATE BURRS.

| | INCHES | | MILLIN | IETERS |
|-----|-----------|-------|----------|--------|
| DIM | MIN | MAX | MIN | MAX |
| Α | 0.071 | 0.087 | 1.80 | 2.20 |
| В | 0.045 | 0.053 | 1.15 | 1.35 |
| С | 0.031 | 0.043 | 0.80 | 1.10 |
| D | 0.004 | 0.012 | 0.10 | 0.30 |
| G | 0.026 | BSC | 0.65 BSC | |
| Н | | 0.004 | | 0.10 |
| J | 0.004 | 0.010 | 0.10 | 0.25 |
| K | 0.004 | 0.012 | 0.10 | 0.30 |
| N | 0.008 REF | | 0.20 | REF |
| S | 0.079 | 0.087 | 2.00 | 2.20 |

GENERIC MARKING DIAGRAM*



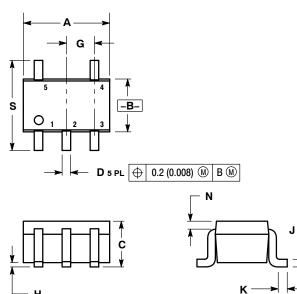
XXX = Specific Device Code

= Date Code

= Pb-Free Package

(Note: Microdot may be in either location)

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



0.50 0.0197 0.65 0.025 0.65 0.025 0.40 0.0157 1.9 mm 0.0748 SCALE 20:1

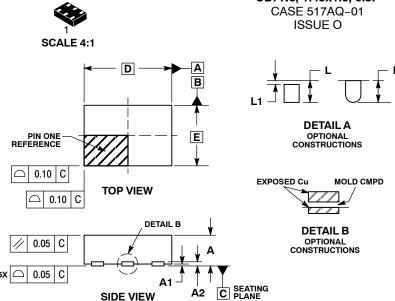
SOLDER FOOTPRINT

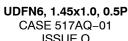
| STYLE 1: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR | STYLE 2: PIN 1. ANODE 2. EMITTER 3. BASE 4. COLLECTOR 5. CATHODE | STYLE 3: PIN 1. ANODE 1 2. N/C 3. ANODE 2 4. CATHODE 2 5. CATHODE 1 | STYLE 4: PIN 1. SOURCE 1 2. DRAIN 1/2 3. SOURCE 1 4. GATE 1 5. GATE 2 | STYLE 5: PIN 1. CATHODE 2. COMMON ANODE 3. CATHODE 2 4. CATHODE 3 5. CATHODE 4 |
|---|--|--|--|--|
| | | | | |

| 5. COLLECTOR | 5. CATHODE | 5. CATHODE I | 5. GATE 2 | 5. CATHODE 4 |
|--|--|--|--|---|
| STYLE 6: PIN 1. EMITTER 2 2. BASE 2 3. EMITTER 1 4. COLLECTOR 5. COLLECTOR 2/BASE 1 | STYLE 7: PIN 1. BASE 2. EMITTER 3. BASE 4. COLLECTOR 5. COLLECTOR | STYLE 8: PIN 1. CATHODE 2. COLLECTOR 3. N/C 4. BASE 5. EMITTER | STYLE 9: PIN 1. ANODE 2. CATHODE 3. ANODE 4. ANODE 5. ANODE | Note: Please refer to datasheet for style callout. If style type is not called out in the datasheet refer to the device datasheet pinout or pin assignment. |

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|------------------|------------------------|---|-------------|
| DESCRIPTION: | SC-88A (SC-70-5/SOT-35 | 63) | PAGE 1 OF 1 |

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DATE 15 MAY 2008

- NOTES:
 1. DIMENSIONING AND TOLERANCING PER
 ASME Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS.

 - DIMENSION & APPLIES TO PLATED TERMINAL AND IS MEASURED BETWEEN 0.15 AND 0.30 mm FROM THE TERMINAL TIP.

| | MILLIMETERS | | | |
|-----|-------------|------|--|--|
| DIM | MIN | MAX | | |
| Α | 0.45 | 0.55 | | |
| A1 | 0.00 | 0.05 | | |
| A2 | 0.07 REF | | | |
| b | 0.20 | 0.30 | | |
| D | 1.45 | BSC | | |
| Е | 1.00 BSC | | | |
| е | 0.50 BSC | | | |
| L | 0.30 | 0.40 | | |
| 11 | | 0.15 | | |

GENERIC MARKING DIAGRAM*



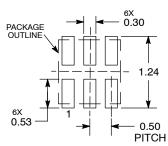
= Specific Device Code Χ

Μ = Date Code

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot " ■", may or may not be present.

е 6X L DETAIL A 6X b 0.10 C A B Ф С ноте з 0.05 **BOTTOM VIEW**

MOUNTING FOOTPRINT



DIMENSIONS: MILLIMETERS

*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

| DOCUMENT NUMBER: | 98AON30313E | Electronic versions are uncontrolle | ' |
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| DESCRIPTION: | UDFN6, 1.45X1.0, 0.5P | | PAGE 1 OF 2 |



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|-------------------------|--|
| 98AON30313E | |

PAGE 2 OF 2

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| ISSUE | REVISION | DATE |
| 0 | RELEASED FOR PRODUCTION. REQ. BY K. VAN TYNE. | 15 MAY 2008 |
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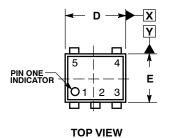
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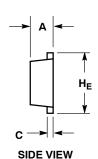


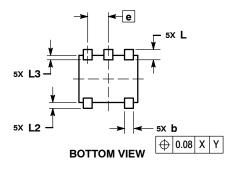
SOT-953 CASE 527AE **ISSUE E**

DATE 02 AUG 2011

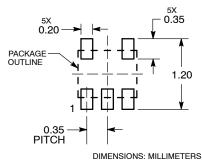








SOLDERING FOOTPRINT*



*For additional information on our Pb-Free strategy and soldering details, please download the ON Semiconductor Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

NOTES:

- DIMENSIONING AND TOLERANCING PER ASME
- Y14.5M, 1994.
 2. CONTROLLING DIMENSION: MILLIMETERS
- MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE
- MINIMUM THICKNESS OF THE BASE MATERIAL.
 DIMENSIONS D AND E DO NOT INCLUDE MOLD
 FLASH, PROTRUSIONS, OR GATE BURRS.

| | MILLIMETERS | | | |
|-----|-------------|------|------|--|
| DIM | MIN | NOM | MAX | |
| Α | 0.34 | 0.37 | 0.40 | |
| b | 0.10 | 0.15 | 0.20 | |
| С | 0.07 | 0.12 | 0.17 | |
| D | 0.95 | 1.00 | 1.05 | |
| E | 0.75 | 0.80 | 0.85 | |
| е | 0.35 BSC | | | |
| HE | 0.95 | 1.00 | 1.05 | |
| L | 0.175 REF | | | |
| L2 | 0.05 | 0.10 | 0.15 | |
| L3 | | | 0.15 | |

GENERIC MARKING DIAGRAM*



= Specific Device Code = Month Code

*This information is generic. Please refer to device data sheet for actual part marking.

Pb-Free indicator, "G" or microdot " ■", may or may not be present.

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